











SN74LV07A

SCES337K-MAY 2000-REVISED OCTOBER 2014

# SN74LV07A Hex Buffers/Drivers With Open-Drain Outputs

#### **Features**

- 2-V to 5.5-V V<sub>CC</sub> Operation
- Typical V<sub>OLP</sub> (Output Ground Bounce)  $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)  $> 2.3 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Outputs are Disabled During Power Up and Power Down With Inputs Tied to V<sub>CC</sub>
- Support Mixed-Mode Voltage Operation on All Ports
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model
  - 200-V Machine Model
  - 1000-V Charged-Device Model

## 2 Applications

- Servers
- Telecom Infrastructures
- TV Set-Top Boxes

## Description

These hex buffers/drivers are designed for 2-V to 5.5-V V<sub>CC</sub> operation.

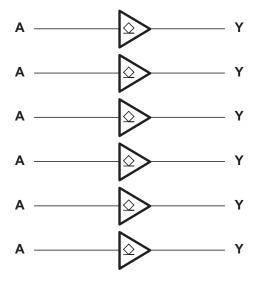
The SN74LV07A device performs the Boolean function Y = A in positive logic.

### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)			
	TVSOP (14)	3.60 mm x 4.40 mm			
	SOIC (14)	8.65 mm × 3.91 mm			
SN74LV07A	SOP (14)	10.30 mm x 5.30 mm			
	SSOP (14)	6.20 mm x 5.30 mm			
	TSSOP (14)	5.00 mm x 4.40 mm			

(1) For all available packages, see the orderable addendum at the end of the data sheet.

## 4 Simplified Schematic





## **Table of Contents**

1	Features 1	9	Detailed Description	7
2	Applications 1	-	9.1 Overview	
3	Description 1		9.2 Functional Block Diagram	
4	Simplified Schematic		9.3 Feature Description	
5	Revision History		9.4 Device Functional Modes	7
6	Pin Configuration and Functions	10	Application and Implementation	8
-	_		10.1 Application Information	
7	Specifications		10.2 Typical Application	
	7.1 Absolute Maximum Ratings	11	Power Supply Recommendations	
	7.2 Handling Ratings	12	Layout	
	7.3 Recommended Operating Conditions		12.1 Layout Guidelines	
	7.4 Thermal Information		•	
	7.5 Electrical Characteristics 5			
	7.6 Switching Characteristics, V <sub>CC</sub> = 2.5 V ± 0.2 V 5	13	Device and Documentation Support	
	7.7 Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V} \dots 5$		13.1 Related Links	10
	7.8 Switching Characteristics, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V} \dots 6$		13.2 Trademarks	10
	7.9 Noise Characteristics		13.3 Electrostatic Discharge Caution	10
	7.10 Operating Characteristics 6		13.4 Glossary	
	, ,	14	Mechanical, Packaging, and Orderable	
_	21		Information	10
8	Parameter Measurement Information 7			

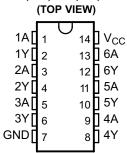
## **5 Revision History**

CI	hanges from Revision J (October 2010) to Revision K	Page
•	Updated document to new TI data sheet format	
•	Deleted Ordering Information table.	······································
•	Added Handling Ratings table	4
•	Changed MAX operating temperature to 125°C in Recommended Operating Conditions table.	4
•	Added Thermal Information table.	!
•	Added Typical Characteristics.	(
•	Added Detailed Description section	
•	Added Application and Implementation section	8
•	Added Power Supply Recommendations and Layout sections	9



## 6 Pin Configuration and Functions

SN74LV07A . . . D, DB, DGV, NS, OR PW PACKAGE



#### **Pin Functions**

Р	IN		PEODINE
NAME	NO.	I/O	DESCRIPTION
1A	1	I	1A Input
1Y	2	0	1Y Output
2A	3	I	2A Input
2Y	4	0	2Y Output
ЗА	5	I	3A Input
3Y	6	0	3Y Output
4A	9	I	4A Input
4Y	8	0	4Y Output
5A	11	I	5A Input
5Y	10	0	5Y Output
6A	13	I	6A Input
6Y	12	0	6Y Output
GND	7	_	Ground Pin
V <sub>CC</sub>	14	_	Power Pin

Copyright © 2000–2014, Texas Instruments Incorporated

Submit Documentation Feedback



## 7 Specifications

## 7.1 Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	7	V
$V_{I}$	Input voltage range <sup>(2)</sup>	-0.5	7	V	
Vo	Voltage range applied to any output in the high-impeda	-0.5	7	V	
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		-35	mA
	Continuous current through V <sub>CC</sub> or GND		±50	mA	

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 7.2 Handling Ratings

			MIN	MAX	UNIT
T <sub>stg</sub>	Storage temperature rang	e	-65	150	°C
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	0	2000	\/
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	0	1000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

## 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT			
V <sub>CC</sub>	Supply voltage		2	5.5	V			
		V <sub>CC</sub> = 2 V	1.5					
.,	High level input valtage	V <sub>CC</sub> = 2.3 V to 2.7 V	V <sub>CC</sub> × 0.7		V			
V <sub>IH</sub>	High level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	$V_{CC} \times 0.7$		V			
		V <sub>CC</sub> = 4.5 V to 5.5 V	V <sub>CC</sub> × 0.7	V <sub>CC</sub> × 0.7				
		V <sub>CC</sub> = 2 V		0.5				
\ /	Low lovel input veltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		$V_{CC} \times 0.3$	V			
$V_{IL}$	Low level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		$V_{CC} \times 0.3$				
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		$V_{CC} \times 0.3$				
VI	Input voltage		0	5.5	V			
Vo	Output voltage		0	5.5	V			
		V <sub>CC</sub> = 2 V		50	μΑ			
ı	Low lovel output ourrent	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2				
OL	Low level output current	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		8	mA			
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		16				
		V <sub>CC</sub> = 2.3 V to 2.7 V		200				
Δt/Δv	Input transition rise and fall rate	V <sub>CC</sub> = 3 V to 3.6 V	100		ns/V			
		V <sub>CC</sub> = 4.5 V to 5.5 V		20				
T <sub>A</sub>	Operating free-air temperature		-40	125	°C			

All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

Product Folder Links: SN74LV07A

<sup>(2)</sup> The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



### 7.4 Thermal Information

			SN74LV07A								
	THERMAL METRIC <sup>(1)</sup>	DB	DGV	NS	PW	UNIT					
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS					
$R_{\theta JA}$	Junction-to-ambient thermal resistance	100.6	112.5	135.2	95.4	128.7					
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	51.8	65.0	57.9	52.9	57.2					
$R_{\theta JB}$	Junction-to-board thermal resistance	54.9	59.9	68.3	51.2	70.7	°C/W				
ΨЈТ	Junction-to-top characterization parameter	25.0	25.0	9.2	17.9	9.3					
ΨЈВ	Junction-to-board characterization parameter	54.7	59.3	67.6	53.8	70.0					

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

#### 7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	SI	N74LV07A		-40°C to 125°C SN74LV07A		
			MIN	TYP MA	X MIN	TYP	MAX	
	I <sub>OL</sub> = 50 μA	2 V to 5.5 V		0	.1		0.1	
V	I <sub>OL</sub> = 2 mA	2.3 V		0	.4		0.4	V
$V_{OL}$	I <sub>OL</sub> = 8 mA	3 V		0.4	4		0.44	V
	I <sub>OL</sub> = 16 mA	4.5 V		0.5	55		0.55	
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V	±1		:1		±1	μA
I <sub>OH</sub>	$V_{I} = V_{IH},$ $V_{OH} = V_{CC}$	5.5 V		±2	.5		±2.5	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V		2	20		20	μA
I <sub>off</sub>	$V_I$ or $V_O = 0$ to 5.5 V	0			5		5	μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V		1.6		1.6		pF

## 7.6 Switching Characteristics, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	1	Γ <sub>A</sub> = 25°C	:	SN74L	/07A	-40°C to 12 SN74LV0		UNIT
	(INPOT) (O	(001701)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	Α	Υ	0 45 -5		6.6 <sup>(1)</sup>	10.4 <sup>(1)</sup>	1	13	1	14	20
t <sub>PHL</sub>	Α	Y	$C_L = 15 pF$		7.5 <sup>(1)</sup>	10.4 <sup>(1)</sup>	1	13	1	14	ns
t <sub>PLH</sub>	Α	Υ	C - F0 pF		11.1	15.2	1	18	1	19	20
t <sub>PHL</sub>	А	Υ	$C_L = 50 pF$		9.6	15.2	1	18	1	19	ns

<sup>(1)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.

## 7.7 Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	AMETER FROM TO LOAD  (INPUT) (OUTPUT) CAPACITANCE		T <sub>A</sub> = 25°C			SN74LV07A		-40°C to 125°C SN74LV07A		UNIT	
	(INPOT)	(001701)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	А	Υ	C 45 x 5		5 <sup>(1)</sup>	7.1 <sup>(1)</sup>	1	8.5	1	9.5	
t <sub>PHL</sub>	Α	Υ	$C_L = 15 \text{ pF}$		5 <sup>(1)</sup>	7.1 <sup>(1)</sup>	1	8.5	1	9.5	ns
t <sub>PLH</sub>	Α	Υ	C <sub>L</sub> = 50 pF		8.2	10.6	1	12	1	13	
t <sub>PHL</sub>	А	Y			6.6	10.6	1	12	1	13	ns

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

Product Folder Links: SN7

Copyright © 2000-2014, Texas Instruments Incorporated



## 7.8 Switching Characteristics, $V_{cc} = 5 V \pm 0.5 V$

operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	TO (OUTPUT)	LOAD CAPACITANCE	٦	Γ <sub>A</sub> = 25°C		SN741	_V07A	-40°C to 12 SN74LV0		UNIT
	(INPUT)	(001201)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	Α	Υ	C 45 pF		3.8	5.5 <sup>(1)</sup>	1	6.5	1	7.2	
t <sub>PHL</sub>	Α	Υ	$C_L = 15 pF$		3.4 <sup>(1)</sup>	5.5 <sup>(1)</sup>	1	6.5	1	7.2	ns
t <sub>PLH</sub>	А	Y	0 50-5		5.7	7.5	1	8.5	1	9.2	
t <sub>PHL</sub>	Α	Υ	$C_L = 50 \text{ pF}$		4.5	7.5	1	8.5	1	9.2	ns

<sup>(1)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.

## 7.9 Noise Characteristics(1)

 $V_{CC}$  = 3.3 V,  $C_L$  = 50 pF,  $T_A$  = 25°C

	PARAMETER	MIN	TYP	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic V <sub>OL</sub>		0.4	0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic VOL		-0.1	-0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic V <sub>OH</sub>		3.2		٧
$V_{IH(D)}$	High-level dynamic input voltage	2.31			٧
$V_{IL(D)}$	Low-level dynamic input voltage			0.99	V

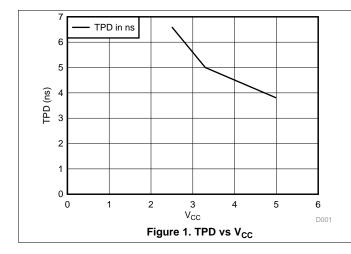
<sup>(1)</sup> Characteristics are for surface-mount packages only.

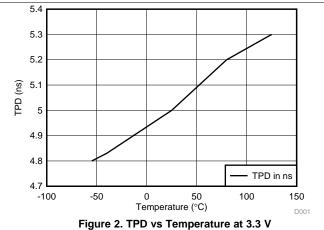
## 7.10 Operating Characteristics

 $T_{\Delta} = 25^{\circ}C$ 

	PARAMETER	TEST C	CONDITIONS	V <sub>CC</sub>	TYP	UNIT
_	Dower dissination constitutes	C 50 pF	f 10 MH=	3.3 V	2.9	۲
$C_{pd}$	Power dissipation capacitance	$C_L = 50 \text{ pF},$	f = 10 MHz	5 V	5.3	p⊦

## 7.11 Typical Characteristics



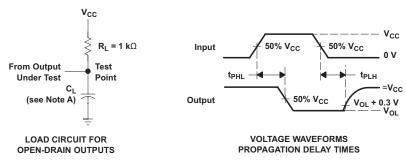


Submit Documentation Feedback

Copyright © 2000-2014, Texas Instruments Incorporated



#### 8 Parameter Measurement Information



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \ \Omega$ ,  $t_f \leq$  3 ns.
- C. The outputs are measured one at a time, with one input transition per measurement.

Figure 3. Load Circuit and Voltage Waveforms

## 9 Detailed Description

#### 9.1 Overview

The outputs of the SN74LV07A device are open drain and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 16 mA at 5-V  $V_{CC}$ . Inputs can be driven from 2.5-V, 3.3-V, or 5-V (CMOS) devices. This feature allows the use of the SN74LV07A device as a translator in a mixed-system environment. This device is fully specified for partial power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, thus preventing a damaging current backflow through the device when it is powered down.

## 9.2 Functional Block Diagram



Figure 4. Logic Diagram, Each Buffer/Driver (Positive Logic)

### 9.3 Feature Description

- · Wide operating voltage range
  - Operates from 2 V to 5.5 V
- Allows up or down voltage translation
  - Inputs and outputs accept voltages to 5.5 V
- I<sub>off</sub> feature
  - Allows voltages on the inputs and outputs when V<sub>CC</sub> is 0 V

#### 9.4 Device Functional Modes

Table 1. Function Table (Each Buffer/Driver)

INPUT A	OUTPUT Y
Н	Н
L	L

Submit Documentation Feedback



## 10 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## 10.1 Application Information

The SN74LV07A device is a low drive, open-drain CMOS device that can be used for a multitude of buffer type functions. The inputs are 5.5-V tolerant. The outputs are open drain and 5.5-V tolerant; thus, allowing the device to translate up to 5.5 V or down to any other voltage between GND and 5.5 V.

## 10.2 Typical Application

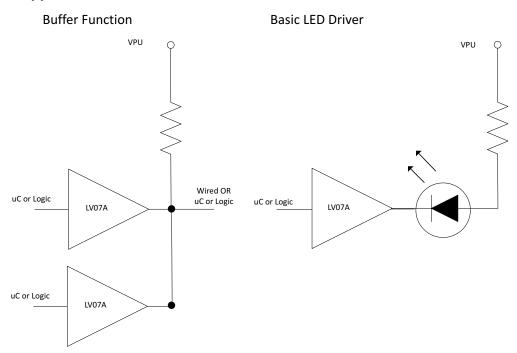


Figure 5. Typical Application Schematic

#### 10.2.1 Design Requirements

This device uses CMOS technology and is open drain, so it has low output drive only. Care should be taken to avoid bus contention, because it can drive currents that would exceed maximum limits. Parallel output drive can create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

#### 10.2.2 Detailed Design Procedure

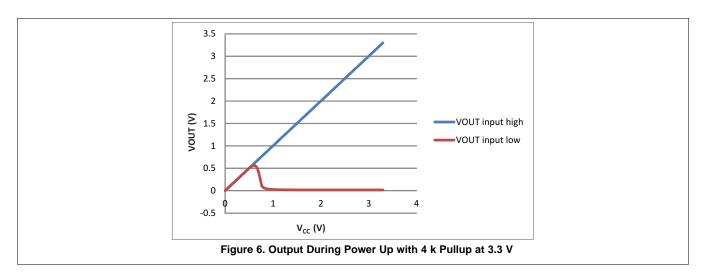
- 1. Recommended Input Conditions:
  - For rise time and fall time specifications, see Δt/ΔV in the Recommended Operating Conditions table.
  - For specified high and low levels, see V<sub>IH</sub> and V<sub>IL</sub> in the Recommended Operating Conditions table.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V<sub>CC</sub>.
- 2. Recommended Output Conditions:
  - Load currents should not exceed 35 mA per output and 50 mA total for the part.

Submit Documentation Feedback



### Typical Application (continued)

#### 10.2.3 Application Curves



## 11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Recommended Operating Conditions. Each V<sub>CC</sub> terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 µF is recommended. If there are multiple V<sub>CC</sub> terminals then 0.01 µF or 0.022 µF is recommended for each power terminal. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 µF and 1 µF are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

### 12 Layout

### 12.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 7 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V<sub>CC</sub>, whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver.

### 12.2 Layout Example

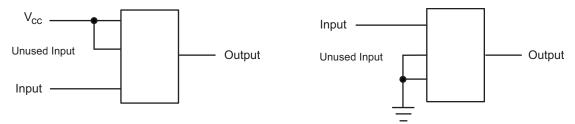


Figure 7. Layout Diagram

Copyright © 2000-2014, Texas Instruments Incorporated Submit Documentation Feedback



## 13 Device and Documentation Support

#### 13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74LV07A	Click here	Click here	Click here	Click here	Click here

#### 13.2 Trademarks

All trademarks are the property of their respective owners.

### 13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LV07A

www.ti.com

m 7-Oct-2025

### **PACKAGING INFORMATION**

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
SN74LV07AD	Obsolete	Production	SOIC (D)   14	-	-	Call TI	Call TI	-40 to 125	LV07A
SN74LV07ADBR	Active	Production	SSOP (DB)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07ADBR.A	Active	Production	SSOP (DB)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07ADGVR	Active	Production	TVSOP (DGV)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07ADGVR.A	Active	Production	TVSOP (DGV)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07ADR	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07ADR.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07ADRG4	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07ADRG4.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07ANS	Obsolete	Production	SOP (NS)   14	-	=	Call TI	Call TI	-	74LV07A
SN74LV07ANSR	Active	Production	SOP (NS)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV07A
SN74LV07ANSR.A	Active	Production	SOP (NS)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV07A
SN74LV07APW	Obsolete	Production	TSSOP (PW)   14	-	=	Call TI	Call TI	-40 to 125	LV07A
SN74LV07APWR	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07APWR.A	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07APWR.B	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07APWRG3	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07APWRG3.A	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07APWRG4	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07APWRG4.A	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07APWRG4.B	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV07A
SN74LV07APWT	Obsolete	Production	TSSOP (PW)   14	-	-	Call TI	Call TI	-40 to 125	LV07A

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.



## PACKAGE OPTION ADDENDUM

www.ti.com 7-Oct-2025

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



www.ti.com 11-Oct-2025

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV07ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LV07ADGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74LV07ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV07ADRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV07ANSR	SOP	NS	14	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
SN74LV07APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV07APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV07APWRG3	TSSOP	PW	14	2000	330.0	12.4	6.85	5.45	1.6	8.0	12.0	Q1
SN74LV07APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



www.ti.com 11-Oct-2025



\*All dimensions are nominal

7 ili dilliciololio die fiorilliai							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV07ADBR	SSOP	DB	14	2000	353.0	353.0	32.0
SN74LV07ADGVR	TVSOP	DGV	14	2000	353.0	353.0	32.0
SN74LV07ADR	SOIC	D	14	2500	353.0	353.0	32.0
SN74LV07ADRG4	SOIC	D	14	2500	353.0	353.0	32.0
SN74LV07ANSR	SOP	NS	14	2000	353.0	353.0	32.0
SN74LV07APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV07APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV07APWRG3	TSSOP	PW	14	2000	366.0	364.0	50.0
SN74LV07APWRG4	TSSOP	PW	14	2000	353.0	353.0	32.0



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



## DGV (R-PDSO-G\*\*)

### 24 PINS SHOWN

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194





#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-150.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.







#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025. Texas Instruments Incorporated